

## 30A Trench Low Barrier Diode

#### ■ Features

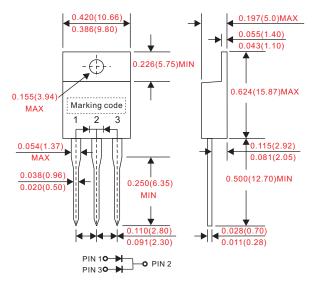
- · Low forward voltage drop.
- Excellent high temperature stability.
- Fast switching capability.
- Suffix "G" indicates Halogen-free part, ex.CST3040CTG.
- Lead-free parts meet environmental standards of MIL-STD-19500 /228

#### ■ Mechanical data

- Epoxy: UL94-V0 rated flame retardant.
- Case: JEDEC TO-220AB molded plastic body over passivated chip.
- Lead : Axial leads, solderable per MIL-STD-202, Method 208 guranteed.
- Polarity: Color band denotes cathode end.
- · Mounting Position : Any.
- Weight: Approximated 2.25 gram.

#### Outline

#### TO-220AB



Dimensions in inches and (millimeters)

## ■ Maximum ratings and electrical characteristics

Rating at  $25^{\circ}$ C ambient temperature unless otherwise specified. Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Parameter	Conditions	Symbol	CST3040CT	UNIT
Marking code			CST3040CT	
Peak repetitive reverse voltage		V <sub>RRM</sub>		
Working peak reverse voltage		V <sub>RWM</sub>	40	V
DC blocking voltage		V <sub>RM</sub>		
Forward rectified current (total device)	T <sub>c</sub> = 110°C	Io	20	А
Forward surge current (per diode)	8.3ms single half sine-wave superimposed on rate load (JEDEC method)	I <sub>FSM</sub>	200	А
Peak repetitive reverse surge current (per diode)	2us - 1kHz	I <sub>RRM</sub>	2	А
Thermal resistance(1) (per diode)	Junction to case	R <sub>eJC</sub>	2	°C/W
Operating and Storage temperature		T <sub>J</sub> , T <sub>STG</sub>	-65 ~ +150	°C

Parameter	Conditions	Symbol	MIN.	TYP.	MAX.	UNIT
Forward voltage drop (per diode)	$I_F = 10A, T_J = 25^{\circ}C$	V <sub>F</sub>			550	mV
	$I_F = 10A, T_J = 125^{\circ}C$			480	500	
I Reverse current (per diode)	$V_R = V_{RRM} T_J = 25^{\circ}C$	- I <sub>R</sub>			0.5	mA
	$V_R = V_{RRM} T_J = 125^{\circ}C$				100	

 $Note: 1. Thermal\ resistance\ from\ junction\ to\ case\ per\ leg,\ with\ heatsink\ size (1.35"\ x\ 0.95"\ x\ 0.18")\ Al-plate.$ 

Document ID: DS-11K7P Issued Date: 2010/05/05 Revised Date: 2012/05/31

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# ■ Rating and characteristic curves

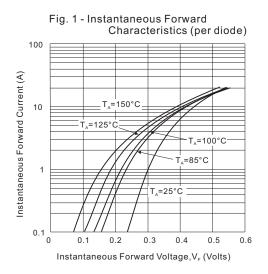


Fig.2 - Forward Current Derating Curve (per diode)

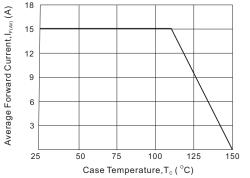
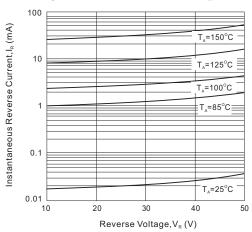


Fig. 3 - Reverse Characteristics (per diode)



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Document ID : DS-11K7P Issued Date : 2010/05/05 Revised Date : 2012/05/31

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